Claims:

- 1. A plasma processing system comprising:
 - a process chamber;
 - an upper electrode assembly;
 - a fluid flow control member; and
- a chuck assembly including a plurality of lift pin assemblies, for lifting the fluid flow control member at at least one location.
- 2. The plasma processing system of Claim 1 wherein the chuck assembly comprises at least one of an RF electrode and an electrostatic clamping electrode.
- 3. The plasma processing system of Claim 1 wherein the fluid flow control member comprises a focus ring.
- 4. The plasma processing system of Claim 1 wherein the fluid flow control member comprises a pumping baffle.
- 5. The plasma processing system of Claim 1 wherein the fluid flow control member comprises an auxiliary focus ring.
- 6. The plasma processing system of Claim 1 wherein lift pins of each of the plurality of lift pin assemblies are lifted simultaneously.
- 7. The plasma processing system of Claim 1 wherein lift pins of each of the plurality of lift pin assemblies are controllable to be lifted individually.
- 8. The plasma processing system of Claim 1 wherein the lift pin assemblies comprise motion actuator hardware, bellows and a seal for separating the motion actuator hardware from a plasma in the plasma chamber.
- 9. The plasma processing system of Claim 1, further comprising a vacuum port located next to at least one of the plurality of lift pin assemblies.

- 10. In a movable focus ring the improvement comprising:a hole for facilitating lifting of the focus ring by lift pins.
- 11. In a movable focus ring the improvement comprising: a recess for facilitating lifting of the focus ring by lift pins.